Percolation, sliding, localization and relaxation in glassy circuits

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There is recent interest in "glassy" systems that have logwide distribution of relaxation rates [1]. For example we note recent works regarding electron dynamics where the effective model is essentially the same as a random walk on a disordered lattice [2, 3]. In such type of model there is a percolation-related crossover to sub-diffusion (in one dimension), or to variable-range-hopping type diffusion (in general) [4?]. This crossover is reflected in the spectral properties of the system. An equivalent point of view regarding percolation is the continuous time random walk (CTRW) with a broad distribution of waiting times [5]. The more general problem of random walk in random environment, where transitions between sites are allowed to be asymmetric, has been explored by Sinai [6], Derrida [7], and followers [5, 8]. Focusing on one-dimensional systems, it turns out that for any small amount of disorder an unbiased spreading becomes subdiffusive. For bias that exceeds a non-zero threshold there is a sliding transition, and the drift velocity becomes nonzero. Considering an N-site ring geometry, we ask what are the implications of the percolation and of the sliding transitions on the relaxation modes of such topologically closed system. A complementary question regarding the "delocalization" of eigenstates of non-Hermitian quantum Hamiltonians has been addressed by Hatano, Nelson, and followers [9–11]. Their main achievement is the realization that the complex spectrum of the non-Hermitian hamiltonian can be deduced from the real spectrum of an associated Hermitian hamiltonian. Various improvements on the method and ensuing analytical results were obtained. For example, the complex spectrum in the thermodynamic limit was found in [12]. An equation for the curve in the complex plane on which the eigenvalues are located and the density of states was found in [13]. Results for special models of one impurity and one way dynamics (maximally asymmetric transition rates) were obtained in [14]. The physical phenomena that inspired this line of work is vortex depinning in type II superconductors [9, 10], yet parallels to non quantum systems were drawn. Such systems include pulling pinned polymers, DNA denaturation [15, 16] and non conservative population biology [17]. We show below that for a conservative "random walk" dynamics the implied spectral properties are dramatically different. Notable "conservative random walkers" are Brownian motors. For example, molecular motors on heterogeneous tracks, such as DNA or RNA [18, 19]. It was found that under an external force and strong disorder, the motor will become localized at preferred positions yet near the stall force, localization occurs for any amount of disorder. These results were obtained by observing the numerically obtained spectrum.

To summarize [19], they use a different method, bypassing the hermitization procedure. The long time behavior of v and D is deduced by numerical observations of the lower edge of the spectrum (small $|\lambda|$). In fact the hermitization procedure

is claimed to obscure the complexity (we found it!). Somehow they do not bridge between complexity of the spectrum and the sliding transition in a purely conservative model. They make some comments regarding complexity and sliding in the following respect. They consider a model where there are two types of unit cells. Each unit cell is made of two bonds. The chain is composed of unit cells drawn from a bimodal distribution. Real eigenvalues only appear due to non conservative diagonal disorder (detachment rate). They do not find an explicit crossover to complexity and do not handle the purely conservative case.

I. STOCHASTIC SPREADING

Diffusive spreading.— Einstein has considered in his thesis the problem of Brownian motion. This can be regarded as a stochastic process in which a particle hops from site to site with some hopping rate w. The rate equation can be written in matrix notation as

$$\frac{d\mathbf{p}}{dt} = \mathbf{W}\mathbf{p},\tag{1}$$

involving a matrix W whose off-diagonal elements are the transitions rates w_{nm} , and with diagonal elements $-\gamma_n$ such that each column sums to zero. For example, in the case of a one-dimensional lattice with near-neighbor hopping

$$W = \begin{bmatrix} -\gamma_1 & w_{1,2} & 0 & \dots \\ w_{2,1} & -\gamma_2 & w_{2,3} & \dots \\ 0 & w_{3,2} & -\gamma_3 & \dots \\ \dots & \dots & \dots & \dots \end{bmatrix}$$
 (2)

with $\gamma_n = \sum_{m(\neq n)} w_{mn}$. Einstein's theory assumes a symmetric matrix W. The diffusion coefficient is $D \sim wa^2$, where w is the average hopping rate between neighboring sites, and a is the average distance between them. The associated negative eigenvalues $\{-\epsilon_k\}$ of the matrix W are characterized by the spectral density

$$\rho(\epsilon) = \text{const } \epsilon^{\mu - 1} \quad \text{(for small } \epsilon)$$
 (3)

where $\mu = d/2$, and d = 1,2,3 is the dimensionality. It is physically appealing to think of W as the Hamiltonian matrix of a particle on a lattice, and then $-\epsilon_k$ are the eigen-energies. Optionally the w_{nm} may represent spring-constants, and then $\omega_k = \sqrt{\epsilon_k}$ are the Debye frequencies of the vibrational modes.

Percolation transition.— The first question that arises is how is Einstein's result affected if the rates come from some wide distribution. The simplest model assumes randomly distributed sites, and rates that depend exponentially on the distance $w \propto \exp(-r/\xi)$. For such a type of model the distribution of the rates is

$$P(w) = \text{const } w^{\alpha - 1} \quad \text{(for small } w\text{)}$$
 (4)

where $\alpha=\xi/a$. If the distance between the sites is increased, α decreases. As the network becomes "glassy" ($\alpha<1$) there is a percolation-related transition to very slow diffusion ("variable range hopping"). This holds for any dimension d>1. For one dimension (d=1) there is a more dramatic transition to sub-diffusion. In the later case the spectral density is no longer $\mu=d/2=1/2$, but

$$\mu[\text{of symmetric matrix}] = \frac{\alpha}{1+\alpha} \le 1/2$$
 (5)

Sinai spreading.— The second question that arises is what happens to Einstein's theory if the transition rates are asymmetric. This question has been addressed by Sinai, Derrida and followers, sometimes called "random walk in random environment". We define the stochastic field as

$$\mathscr{E}_{m \sim n} \equiv \ln\left(\frac{w_{nm}}{w_{mn}}\right), \quad (n \neq m)$$
 (6)

such that the ratio of "backward" to "forward" transitions equals a Boltzmann factor $e^{-\mathscr{E}}$. For the purpose of presentation we assume that the stochastic field has box distribution within $[s-\sigma,s+\sigma]$. The average value s, the so called affinity, determines the direction of the drift velocity $v=v_{\sigma}(s)$. It is well known that by a similarity transformation the W of an *open* chain becomes a symmetric matrix H. The associated spectrum $\{-\epsilon_k\}$ consist of real negative values, and is characterized by a spectral density $\rho(\epsilon)$ that is discussed below.

Sliding transition.— Consider a sample of N sites. For $s \ll 1/N$ the Einstein relation implies that v/D = s. For larger s the ratio becomes smaller, and eventually for a very large s it saturates $v/D \rightarrow 2/a_{\sigma}$. The length scale a_{σ} depends on the disorder σ , and equals the lattice constant in the absence of disorder $(a_0 = a)$. In the limit $N \to \infty$ it has been established that $v_{\sigma}(s) = 0$ up to some critical value s_1 . For $s > s_1$ the drift velocity becomes finite, which we call "sliding transition". The s dependence of the diffusion coefficient $D = D_{\sigma}(s)$ is more complicated: it is vanishingly small up to some value $s_{1/2}$, then it becomes infinitely large up to some critical value s_2 , while for larger s it becomes finite. The sliding-transition threshold s_{μ} is determined solely by the μ th moment of $e^{-\mathcal{E}}$, and is not affected by the P(w) distribution. By inverting the relation $s = s_{\mu}$ we get the exponent that characterizes the spectral density $\rho(\epsilon)$, namely

$$\mu[\text{of asymmetric matrix}] = \mu_{\sigma}(s) \in [0, \infty]$$
 (7)

This implies that the spreading process is anomalous. By definition for $s > s_{\infty}$ we get $\mu = \infty$. For the assumed box distribution $s_{\infty} = \sigma$. The $\mu = \infty$ value means that a gap is opened: the lowest eigenvalue has a non-zero *N*-independent finite value. For zero disorder $\epsilon_0 = v^2/(4D) \propto s^2$ is the characteristic rate of drift limited relaxation, while for very large disorder $\epsilon_0 \propto \exp[(s-\sigma)/2]$ is the minimal transition rate of the network.

Relaxation.— We close an *N*-site chain into a ring. Now a topological aspect is added to the problem, and one wonders what are the relaxation modes of the system. It should be clear that in a closed system the lowest eigenvalue is always $\lambda_0 = 0$, while all the other eigenvalues $\{-\lambda_k\}$ have negative

real part, and may have an imaginary part as well. Complex eigenvalues imply that the relaxation is not over-damped: one would be able to observe an oscillating density during relaxation. The work of [11], regarding the dynamics that is generated by non-Hermitian quantum Hamiltonians, has considered what happens to the spectrum of a non-conservative matrix \boldsymbol{W} whose diagonal elements γ_n are fixed. As s (as defined after equation (6)) is increased beyond a threshold value s_c , the eigenvalues in the middle of the spectrum become complex. As s is further increased beyond some higher threshold value, the spectrum becomes fully complex. In Fig.3 we see that this is not the case in our system: (a) The delocalization starts at the bottom of the band; (b) Asymptotically only a finite fraction of the spectrum becomes complex. We name the latter effect saturation of complexity.

II. SCOPE

Our objective is to understand how the spectral properties of the W matrix are affected as the affinity s is increased. A crucial observation is that the conservative property of the matrix implies that s affects not only the stochastic field, but also the diagonal elements. As in the work of [11] we can transform W into a non-hermitian H matrix. This matrix features the following properties: (i) Off-diagonal disorder characterized by α ; (ii) An affinity parameter s. (iii) Diagonal disorder that is implied by the conservativity. It is the last property that implies a dramatically different spectral scenario. In particular we would like to address the following questions: (1) How does the relaxation rate of the system depend on s? (2) What determines the threshold s_c for getting a complex quasi-continuum? (3) Why is there, and what determines the saturation of complexity? (4) How is the sliding transition reflected in the spectrum? (5) How is the percolation transition reflected in the spectrum?

In order to answer the above questions we translate the spectral problem into the language of Electrostatics in the two dimensional complex plane. We first address the simplest problem of a clean N-site ring with sparse disorder. We explain that $s_c \sim 2\sigma/N$, which is the field required to overcome the weakest link. Then we discuss a fully disordered ring. We show how the sliding transition thresholds s_μ are expressed in the spectral properties. In particular we show that $s_c \to s_{1/2}$, which is the field required to get a sliding transition for D. For $s > s_\infty$ the real spectrum of an open chain is gapped. But for a closed ring the delocalization transition leads to a non-gapped complex λ -spectrum, that exhibits complexity saturation. We explain how the percolation-related transition affects the delocalization process.

III. OUTLINE

- Diffusion and relaxation (λ_1 vs s)
- The secular equation for λ_k
- The real spectrum ϵ_k (discussing μ_s and μ_{α})

- The complex spectrum Electrostatics
- Determination of s_c white vs sparse disorder
- Complexity diminishes the real gap for $s > s_{\infty}$
- Complexity saturation for $s \gg s_{\infty}$

Supplementary

- Sliding transition the definition of s_{μ} .
- The similarity transformation (definition of H)
- The formula for the spectral determinant.
- Clean ring
- Ring with weak link ("g")
- Ring with sparse disorder
- Ring with white disorder ("French")
- Step by step electrostatics

IV. DIFFUSION AND RELAXATION

Consider a stochastic process on an N-site ring with lattice spacing a=1, that is generated by a rate equation with near-neighbor hopping as described by the matrix W of equation (2), where the site index n is defined modulo N. For convenience we use the following notations:

$$\overrightarrow{w}_n = w_{n+1,n} = w_n e^{+\mathscr{E}_n/2} \tag{8}$$

$$\overleftarrow{w}_n = w_{n,n+1} = w_n e^{-\mathscr{E}_n/2}$$
 (9)

For a clean ring (no disorder) the stochastic field is uniform $(\mathscr{E} = s)$ and all the couplings are the same $(w_n = w)$. The drift velocity and the diffusion coefficient are

$$v_0(s) = (\overrightarrow{w} - \overleftarrow{w}) = 2w \sinh(s/2)$$
 (10)

$$D_0(s) = \frac{1}{2} (\overrightarrow{w} + \overleftarrow{w}) = w \cosh(s/2)$$
 (11)

The continuum limit is transparent, and corresponds to the solution of a diffusion equation with a drift term. It is easy to see that the eigenvalues $\{-\lambda_n\}$ of the W matrix are

$$\lambda_n = 2w \left[\cosh\left(\frac{s}{2}\right) - \cos\left(\frac{2\pi}{N}n + i\frac{s}{2}\right) \right]$$
 (12)

The non-equilibrium steady state (NESS) is associated with $\lambda_0=0$. The complexity of the other eigenvalues implies that the relaxation process in not over-damped. Even without any mathematics it is quite clear that the relaxation rate Γ is limited by the lowest diffusion mode, namely

$$\Gamma = \operatorname{Re}[\lambda_1] = \left(\frac{2\pi}{N}\right)^2 D \tag{13}$$

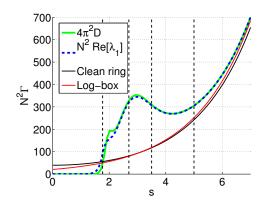


FIG. 1. The real part of the gap of the complex spectrum $\Gamma = \text{Re}[\lambda_1]$ vs. s for N=1000 sites and log-box field disorder with $\sigma=5$. The non monotonic dashed blue line was obtained by numerically diagonalization, whereasthe solid green was obtained by calculating the diffusion coefficient as in [20]. The monotonic lines correspond to the limits if a clean ring equation (13) (black) and $s>s_{\infty}$, equation (38) (red). The vertical dashed lines from left to right are $s_{1/2}$, s_1 , s_2 and s_{∞} .

It is also physically clear that if the ring is "opened", or optionally if one of the links is removed, then the relaxation becomes drift-limited. The result is

$$\Gamma = 2w \left[\cosh \left(\frac{s}{2} \right) - 1 \right] \sim \frac{v^2}{4D} \tag{14}$$

It is important to realize that in the latter case we have a "gap" in the spectrum, meaning that λ_1 does does not diminish in the $N \to \infty$ limit.

In Fig.1 we calculate v(s) and D(s) for a ring with disorder, deduce from it Γ using equation (13), and compare with the numerically determined $\text{Re}[\lambda_1]$. We deduce that the non-monotonic behaviour of Γ can be explained by the known theory of the sliding transition. The question arises whether the sliding transition affects also the global properties of the spectrum. In order to address this question we have to analyze the secular equation that is associated with the matrix W.

V. THE SECULAR EQUATION

By similarity transformation of W one obtains

$$\tilde{\boldsymbol{W}} = \text{diagonal}\{-\gamma_n\} + \text{offdiagonal}\{w_n e^{\pm s/2}\}$$
 (15)

where the " \pm " are for the "forward" and "backward" transitions respectively. Note that the statistics of the \mathcal{E}_n is still hiding in the diagonal elements. The associated symmetric matrix \boldsymbol{H} is defined by setting s=0. Then one can define a spectral determinant S(z) and associated spectrum as follows:

$$S(z) = \det(z - H) = \prod_{k} (z + \epsilon_k)$$
 (16)

If the system is an *N*-periodic infinite lattice, then W is similar to H by "gauge" transformation, hence one can regard the $\{-\epsilon_k\}$ as the spectrum of an open chain. But if the system is

an N-periodic ring (periodic boundary conditions) then s cannot be "gauged" away. Still there is a simple relation [21] that relates the spectral determinant of W to that of H. Namely,

$$\det(z - W) = S(z) - S_0 \equiv \prod_k (z + \lambda_k)$$
 (17)

where

$$S_0 = 2 \left[\cosh \left(\frac{Ns}{2} \right) - 1 \right] \prod_n w_n \tag{18}$$

The roots $z = -\lambda_k$ have real negative part, but may be complex in general. The lowest eigenvalue $\lambda_0 = 0$ corresponds to the non-decaying non-equilibrium steady state (NESS). It is implied that

$$S(0) = S_0$$
 implication of conservativity (19)

We emphasize that the latter property is not true for a general non-Hermitian matrix, neither is the "positivity" of the λ_k . This has far reaching implications: in particular it should be clear that the NESS is an extended state, hence it follows that the localization length has to diverge in the limit $\lambda \to 0$. This is in essence the difference between the conventional Anderson model (Lifshitz tails at the band floor) and the Debye model (phonons at the band floor).

From the above it follows that the secular equation for the λ spectrum can be written as

$$\prod_{k} \left(\frac{z + \epsilon_{k}(s)}{\overline{w}} \right) = 2 \left[\cosh \left(\frac{Ns}{2} \right) - 1 \right]$$
 (20)

where \overline{w} is the geometric average of all the rates. The affinity s affects both the ϵ_k and the right hand side.

VI. THE REAL SPECTRUM

The main observation regarding the real spectrum ϵ_k of the associated symmetric matrix H is that for $s < s_{\infty}$ it is gapless and for $s > s_{\infty}$ it is gapped. This can be seen both in the spetcral density and in the electrostatic potential along the real axis. Recall that $\rho(\epsilon) \sim \epsilon^{\mu-1}$. Consider first the case $\alpha \gg 1$, the percolation aspect is absent and $\mu = \mu_s$. The simplest case is for $s > s_{\infty}$, where a gap opens up at $\epsilon_0 = e^{(s-\sigma)/2}$ and the spectral density is distributed log-box, $\rho(\epsilon) = N/\sigma\epsilon$. This holds as long as $\alpha \gg 1$. The interesting case is when $\alpha \lesssim 1$ and $s < s_{\infty}$, now there is a crossover in the spectrum between two anomalous behaviours. The bottom of the band is detemined by μ_s and the top of the band by μ_{α} , as show in Fig.2. As α decreases, the μ_s determined region becomes smaller. This crossover is analogous to regular diffusion, where there is a crossover from short time, diffusion limited spreading to long time drift limited spreading. In our case the crossover is from low energy (long time) sliding (μ_s) to high energy (short time) percolation limited diffusion μ_{α} .

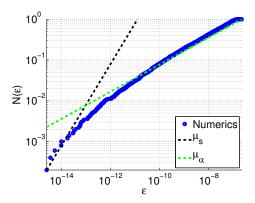


FIG. 2. A representitive case for anomalous diffusion. The integrated density of states is shown for $\mu_{\alpha}=1/3$ and $\mu_{s}=1$, $\sigma=2$ and N=5000 sites. The blue points are are results of numerical diagonalization. There is a crossover in the spectrum from sliding (dashed black line corresponds to μ_{s}) to percolation (dashed green line corresponding to μ_{α}).

VII. ELECTROSTATICS

In order to get an insight into the secular equation we define an "electrostatic" potential as follows:

$$\Psi(z) = \sum_{k} \ln \left(\frac{z - \epsilon_k}{\overline{w}} \right) \equiv V(x, y) + iA(x, y)$$
 (21)

where z = x + iy. Note that compared with equation (15) we have flipped the sign convention $(z \mapsto -z)$. The potential for a given charge distribution $\rho(x)$ is $V(x,y) = \frac{1}{2} \int \ln \left[(x-x')^2 + y^2 \right] \rho(x') dx'$ and along the real axis

$$V(\epsilon) = \int \ln(\epsilon - x) \rho(x) dx$$
 (22)

The constant V(x,y) curves correspond to potential contours, along which |S(z)| is constant, and the constant A(x,y) curves corresponds to stream lines, along which the phase of S(z) is constant. The derivative $\Psi'(z)$ corresponds to the field, which can be regarded as either electric or magnetic field up to a 90deg rotation. Using this language the secular equation takes the form

$$V(x,y) = V(0); \quad A(x,y) = 2\pi * \text{integer}$$
 (23)

Namely the roots are the intersection of the field lines with the potential contour that goes through the origin. From the preceding section we know that the potential at the origin is

$$V(0) = \ln \left[2 \cosh \left(\frac{Ns}{2} \right) - 2 \right] \tag{24}$$

From a straightforward electrostatic calculation we find that for a charge density that is given by equation (3) with some cutoff ϵ_c , the derivative of the electrostatic potential at the origin is given by (see supplementary material for derivation)

$$V'(0) = \lim_{\epsilon \to 0^+} \mu \left(\frac{\epsilon}{\epsilon_c}\right)^{\mu} \pi \cot(\pi \mu)$$
 (25)

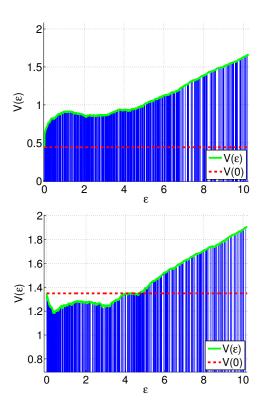


FIG. 3. The electrostatic potential along the real axis. Top panel: $s < s_{1/2}$, the spectrum is real and localized. Bottom panel: $s > s_{1/2}$, the bottom of the band is delocalised and complex. Here N = 1000, $\sigma = 5$ for the top panel we used $s = s_{1/2}/2$, for the bottom panel, $s = s_1$.

Indicating that the sign changes from positive to negative at $\mu = 1/2$.

Let us make a few observations regarding the potential $V(\epsilon)$ along the real axis. For an illustration see Fig.3. Clearly if the envelope of $V(\epsilon)$ is above the V=V(0) line, then the spectrum is real, and the λ_k are roughly the same as the ϵ_k , shifted a bit to the left. The second observation is that the envelope of $V(\epsilon)$ is positive in segments where the ϵ_k forms a quasicontinuum. This follows from the observation that $(1/N)V(\epsilon)$ equals the inverse localization length [11]. In the case under study the quasi-continuum starts at $\epsilon_s=0$ for $s< s_\infty$ (Fig.3), and at finite ϵ_s for $s> s_\infty$ (Fig.5). If follows that the threshold s_c for getting a complex quasi-continuum is either V'(0)<0 or $V(\epsilon_s)< V(0)$ respectively. In the former case it follows from equation (26) that $s_c=s_{1/2}$.

VIII. DETERMINATION OF s_c - WHITE VS SPARSE DISORDER

The simplest case to exhibit a crossover to a complex spectrum is that of a single defect. There are two types of defects, either in the couplings w_n or in the fields \mathcal{E}_n . The details are slightly different, but the analysis is essentially the same. Consider first a single defect in the couplings, such that $w_1 = g$, $w_{n \neq 1} = 1$ where $g \ll 1$. The spectrum of the associ-

ated Hermitian matrix \boldsymbol{H} is composed of a single state ϵ_1 and a quasi-continuum which begins at $\epsilon_s > \epsilon_1$. The single state is pushed down from the quasi-continuum such that (From numerical experiments, I still don't have the exact physical argument) $\epsilon_s = \epsilon_1/g = s^2/4g$. The potential at ϵ_s due to the continuum is zero and the potential there, generated by ϵ_1 is (Assuming $s \ll 1$, $N \gg 1$)

$$V(\epsilon_s) = \ln \left| \frac{\epsilon_s - \epsilon_1}{g} \right| \approx \ln \left(\frac{s^2}{4g^2} \right)$$
 (26)

Complex eigenvalues appear when $V(\epsilon_s) < V(0)$, leading to the equation for s_c

$$1 + \frac{1}{2} \left(\frac{s}{2g} \right)^2 = \cosh\left(\frac{Ns}{2} \right) \tag{27}$$

The exact equation, derived from the continuum limit (see supplementary material) is

$$\sqrt{1 + \left(\frac{s}{2g}\right)^2} = \cosh\left(\frac{Ns}{2}\right) \tag{28}$$

If there are M defects ("sparse" disorder) then there are M states that are separated from the continuum and they are equal in the vicinity of s_c (numerically verified), so $V(\epsilon_s) \approx M \ln(s^2/4g^2)$ and the equation for s_c is

$$\sqrt{1 + \left(\frac{s}{2g}\right)^{2M}} = \cosh\left(\frac{Ns}{2}\right) \tag{29}$$

For a defect in the stochastic field, all of the transition rates are $e^{\pm s/2}$ except for a single bond where the rates are $e^{\pm (s-\sigma)/2}$. As a result there are 4 different decay rates

$$\gamma_0 = 2e^{-\sigma/2}\cosh(s/2),$$
 (30)

$$\gamma_1 = 2\cosh(s/2) \tag{31}$$

$$\gamma_2 = e^{s/2} + e^{-(s-\sigma)/2} \tag{32}$$

$$\gamma_3 = e^{(s+\sigma)/2} + e^{-s/2}$$
 (33)

The spectrum ϵ_k of the symmetric matrix H is composed of a continuum in the range $2\cosh(s/2)\pm 2$ with three additional states: γ_0 is beneath the continuum while γ_2, γ_3 are above the continuum by a factor of $\exp(\sigma/2)$. As in the previous model, the continuum contributes zero to the potential at ϵ_s . The charges above the continuum contribute $V(\epsilon_s) = \ln \gamma_2 + \ln \gamma_3 \approx \sigma$. From the requirement $V(\epsilon_s) < V(0)$, one gets

$$s_c = \frac{2\sigma}{N} \tag{34}$$

IX. COMPLEXITY DIMINISHES THE REAL GAP FOR $s>s_{\infty}$

As we discussed, the spectrum of H is gapped for $s > s_{\infty}$, with a quasi continuum beginning at $\epsilon_0 \propto \exp[(s - \sigma)/2]$.

However, the gap of the complex spectrum is diminished and is given by the expression

$$\operatorname{Re}[\lambda_1] \approx \frac{2\pi^2}{N^2} e^{s/2 - s_{1/2}} \cosh\left(\frac{\sigma}{2}\right)$$
 (35)

The gap grows with s as expected, but diminishes as $1/N^2$. To obtain this expression we use the 2D electrostatics picture previously described. The density of states is $\rho(\epsilon) = N/\sigma\epsilon$, where $\epsilon \in [a,b]$ and $a = \exp[(s-\sigma)/2]$, $b = \exp[(s+\sigma)/2]$. The equipotential contour, V(x,y) = V(0) is approximately a parabola near the origin (see Fig.5 for an illustration), so $x = Cy^2$ should solve the equation. On the other hand, V(x,y) can be expanded near the origin

$$V(x,y) = \frac{1}{2} \int_{a}^{b} \ln((x-X)^{2} + y^{2}) \rho(X) dX$$
 (36)

$$\approx C_0 - C_1 x + \frac{1}{2} C_2 y^2 \tag{37}$$

where the coefficients C_n are defined

$$C_n = \int_a^b \frac{1}{x^n} \rho(x) dx \tag{38}$$

Notice that $C_0 = V(0)$, $C_1 = E_x(x,0)$. Since we are interested in the contour V(x,y) = V(0,0), we obtain

$$x = \frac{1}{2} \frac{C_2}{C_1} y^2 \tag{39}$$

For the given density of states we obtain

$$C = \frac{1}{2} \frac{C_2}{C_1} = \frac{1}{2} e^{-s/2} \cosh\left(\frac{\sigma}{2}\right)$$
 (40)

The gap is determined by integrating the electric field, $\vec{E}(x,y) = -\vec{\nabla}V$, along the parabola of equation (43)

$$\int_{0}^{\sqrt{Re[\lambda_{1}]/C}} \left| \vec{E}(x,y) \right| dy = 2\pi \tag{41}$$

This is equivalent, through Cauchy Riemann, to the requirement $A(Re[\lambda_1],0)=2\pi$. The integrand is approximated by $|\vec{E}(x,y)|\approx |\vec{E}(0,0)|$ by which we obtain an estimate for the gap

$$\operatorname{Re}[\lambda_1] \approx \frac{4\pi^2 C}{\left|\vec{E}(0,0)\right|^2} = \frac{2\pi^2}{N^2} e^{s/2 - s_{1/2}} \cosh\left(\frac{\sigma}{2}\right)$$
 (42)

The same derivation can be repeated for density of states characterized by the exponent μ to obtain (see supplementary)

$$\operatorname{Re}[\lambda_1] \sim \frac{1}{N^2} \frac{(\mu - 1)^3}{\mu^2 (\mu - 2)} \frac{1 - \left(\frac{a}{b}\right)^{\mu - 2}}{\left(1 - \left(\frac{a}{b}\right)^{\mu - 1}\right)^3} b^{1 - 2\mu} \tag{43}$$

The potential along the real axis for the log-box case can be computed analytically

$$V(\epsilon) = \ln(|\epsilon - b|) \ln\left(\frac{b}{\epsilon}\right) + \ln(|\epsilon - a|) \ln\left(\frac{\epsilon}{a}\right) + (44)$$
$$+ \operatorname{Li}_{2}\left(1 - \frac{b}{\epsilon}\right) + \operatorname{Li}_{2}\left(1 - \frac{a}{\epsilon}\right) \tag{45}$$

X. COMPLEXITY SATURATION FOR $s \gg s_{\infty}$

The secular equation for the eigenvalues is given by equation (20). In the nonconservative case, the eigenvalues of H do not depend on s, thus raising s will eventually make the entire spectrum complex. For a conservative matrix, however, $V(\epsilon)$ is also a function of s, so increasing s raises $V(\epsilon)$ at the same rate. Due to the conservative property, the eigenvalues of the associated hermitian martix, ϵ_j grow proportionaly to e^s . Increasing $s \to s + \Delta s$, we have

$$\sum_{k} \ln \left(\frac{z - \epsilon_k e^{\Delta s}}{\overline{w}} \right) = \ln \left[2 \cosh \left(\frac{(s + \Delta s)N}{2} \right) - 2 \right]$$
 (46)

$$\sum_{k} \ln \left(\frac{ze^{-\Delta s} - \epsilon_{k}}{\overline{w}} \right) + N\Delta s = \ln \left[2 \cosh \left(\frac{sN}{2} \right) - 2 \right] + N\Delta s \quad (47)$$

but z is just a dummy variable, so we can redefine $z := ze^{-\Delta s}$ and the equation is unchanged. Thus increasing s does not change the number of complex solutions, as shown in Fig.6.

To estimate the saturation value of the fraction of complex eigenvalues, we assume $s \gg s_{\infty}$. The eigenvalues have a log-box distribution so the potential along the real axis is

$$V(\epsilon) = \int_{a}^{b} \ln|\epsilon - \epsilon'| \rho(\epsilon') d\epsilon' =$$

$$\int_{a}^{\sigma} \left| \frac{(\epsilon + \epsilon')^{2}}{(\epsilon + \epsilon')^{2}} \right| (48)$$

$$= \int_{-\sigma}^{\sigma} \ln \left| e^{(s+\mathscr{E})/2} - e^{(s+\mathscr{E}_c)/2} \right| \rho(\mathscr{E}) d\mathscr{E} = (49)$$

$$= \frac{N}{2\sigma} \int_{-\sigma}^{\sigma} \ln \left| e^{(s+\mathcal{E}_c)/2} - e^{(s+\mathcal{E})/2} \right| d\mathcal{E}$$
 (50)

Define \mathscr{E}_c such that the eigenvalues with \mathscr{E} in the range $-\sigma < \mathscr{E} < \mathscr{E}_c$ are complex, \mathscr{E}_c is determined by the equation $V(\epsilon = e^{(s+\mathscr{E}_c)/2}) = V(0) = sN/2$, leading to

$$\int_{-\pi}^{\sigma} \ln \left| e^{(s+\mathscr{E})/2} - e^{(s+\mathscr{E}_c)/2} \right| d\mathscr{E} = 0$$
 (51)

Clearly, \mathcal{E}_c depends only on σ (Fig.6). The fraction of complex eigenvalues is just

$$n = \frac{\int_{a}^{\epsilon_{c}} \frac{1}{\epsilon} d\epsilon}{\int_{a}^{b} \frac{1}{\epsilon} d\epsilon} = \frac{1}{\sigma} \ln \left(\frac{\epsilon_{c}}{a} \right) = \frac{\mathscr{E}_{c} + \sigma}{2\sigma}$$
 (52)

If instead of a lattice we had a continuous problem and the field disorder was "white noise", the electrostatic potential would be different, as in [8]. It has a peculiar trait that $V(\epsilon \to \infty) = \mathrm{const.}$ the potential reaches a constant value, implying that the entire spectrum becomes complex at once (Fig.6).

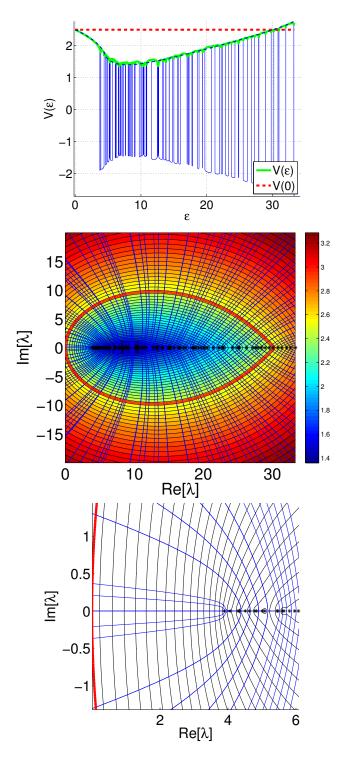


FIG. 4. Top: The electrostatic potential along the real axis, $V(\epsilon)$. The green points are the result of numerical diagonalization, the dashed blue line is the analytical result assuming $\rho = N(\sigma x)^{-1}$, equation(39). The stars indicate the position of the "charges", which are the eigenvalues of the associated Hermitian matrix, ϵ_j . Middle: Field lines and potential of the corresponding electrostatic problem in the entire complex plane. The points of intersection of the field lines (thin blue lines) with the contour $V(\lambda) = V(0)$ (thick red contour) are the solutions to the secular equation. Bottom: Zoom in on the origin. The red line is the equipotential line $V(\lambda) = V(0)$. The gap in the spectrum of H (black stars) is large, but the real gap in the complex spectrum, (intersection of the contour V = V(0) and the first field line) diminishes as $1/N^2$. Here N = 100 sites, $\sigma = 2$ and s = 5.

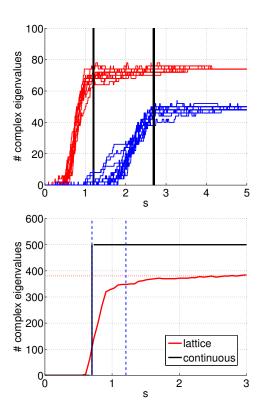


FIG. 5. Top: Number of complex eigenvalues vs. s for N=100 sites. Each red line corresponds to a different realisation of field disorder with $\sigma=3$ (red) and $\sigma=5$ (blue), and $\alpha=\infty$. The black vertical lines are at values of $s_1(\sigma)$ at which the sliding transition occurs. Bottom: Number of complex eigenvalues vs. s for N=500 sites and $\sigma=5$ (red) vs. the result of the continuous, white noise, problem (black step function). The vertical dashed lines are $s_{1/2}$ and s_1 . The dotted horizontal red line is the estimated saturation value, equation (53).

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ACKNOWLEDGEMENTS

This research has been supported by by the Israel Science Foundation (grant No. 29/11).

(61)

A. Appendix - Finding the sign of V'(0)

To derive equation (26) we assume an integrated density of states corresponding to equation (3), $\mathcal{N}(\epsilon) = (\epsilon/\epsilon_c)^{\mu}$, where ϵ_c is some cutoff due to the discreteness of the lattice. The electrostatic potential along the real axis is given by (integration by parts of equation (23))

$$V(\epsilon) = -\int_0^{\epsilon_c} \frac{\mathcal{N}(x)}{x - \epsilon} dx \tag{53}$$

and the derivative with respect to ϵ at the origin is (after integrating by parts)

$$V'(0) = \lim_{\epsilon \to 0^+} \int_0^{\epsilon_c} \frac{\rho(x)}{x - \epsilon} dx =$$
 (54)

$$= \lim_{\epsilon \to 0^+} \frac{\mu}{\epsilon_c^{\mu}} \int_0^{\epsilon_c} \frac{x^{\mu - 1}}{x - \epsilon} dx = \frac{C}{\epsilon_c}$$
 (55)

The integral converges for $\mu < 1$. To calluate C we first substitute $z = x/\epsilon$, such that

$$C = \lim_{z_c \to \infty} \frac{\mu}{z_c^{\mu - 1}} \int_0^{z_c} \frac{z^{\mu - 1}}{z - 1} dz$$
 (56)

The integral can be written in terms of Incomplete Euler Beta functions defined as

$$B_u(a,b) = \int_0^u x^{a-1} (1-x)^{b-1} dx$$
 (57)

However one must be careful and take only the Cauchy principal part

$$I = \int_{0}^{u} \frac{x^{\mu - 1}}{x - 1} dx =$$

$$= \lim_{\varepsilon \to 0} \left[\int_{0}^{1 - \varepsilon} x^{\mu - 1} (1 - x)^{-1} dx + \int_{1 + \varepsilon}^{u} x^{\mu - 1} (1 - x)^{-1} dx \right]$$

$$= \lim_{\varepsilon \to 0} \left[B_{1 - \varepsilon} (\mu, 0) - B_{1 - \varepsilon} (1 - \mu, 0) \right]$$

$$= \psi (1 - \mu) - \psi (\mu) = \pi \cot(\pi \mu)$$
(61)

where $\psi(z)$ is the digamma function and the last equality was obtained by the reflection formula. To go from the second to the third line we made the substitution t = 1/x and took the limit $u \to \infty$. It is clear that C and thus $V'(0^+)$ changes sign from positive to negative at $\mu = 1/2$.

- **B.** Sliding transition the definition of s_{μ}
- The similarity transformation (definition of H)
 - D. The formula for the spectral determinant
 - E. Clean ring
 - Ring with weak link "g"
 - Ring with sparse disorder
 - Ring with white disorder (French)
 - Step by step electrostatics